SEMISHARE-X12

Semi Automatic Probe Station System Introduction



Advanced wafer prober testing technology



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SEMISHARE-X12 X8 X6 Semi Automatic Probe Station System Introduction





Software Automation

- Automatic Wafer align, automatic die size measurement, automatic Wafer Map creation etc.
- One-button mechanical accuracy calibration, support micron-level pad probing
- Automatic temperature compensation
- Convenient system integration

Six Axis Positioner (Optional)

- Integrated scan routines for fiber optic alignment
- Ideal for applications in silicon photonics
- Extensive software package
- Direct detection of the optical signal
- Position sensors for high accuracy and operational reliability
- Automatic alignment of several fibers in <1s

 Optimal EMI, Spectral noise and light shielding test environment Provides the best low noise and low leakage current capacity

Vibration Isolation Integration

Built-in integrated high-performance vibration isolation platform, external isolation bar to avoid vibration caused by operators Fast vibration recovery time <1s for fast die to die testing Fully ergonomic design

Integrated Control System

Provide faster, safer and more convenient prober control makes the prober and tester work more closely

1.Equipment Principle

SEMISHARE X12(X series) semi-automated probe station is designed for testing 12 inch wafer under -60-300 °C environment. It connects wafer and tester through probe tip/probe card and cables. The input electrical signal is loaded on the chip and the output signal is measured. By calculating, analyzing and classifying, the testing result is fed back to the PC and inkjet system, then defective chips will be marked. The classifying and marking method can be set according to customer requirements. After a die' s testing is completed, the chuck will move to the next die and the next test cycle is performed in sequence.

2.Equipment use & function

SEMISHARE X12 (X Series) is a semi-automated probe station that integrates electrical, light,microwave etc. test functions. It is specialized in 12-inch Si Wafer testing and also compatible with 8 inch, 6 inch GaN, SiC wafers. It can work 24X7 hours and can load different temperatures to meet customer' high and low tempera ture demand.

X12 can be equipped with different testers to meet I-V,C-V, optical signals, RF, and 1/F noise test. It is a comprehensive multi-functional semi-automatic probe system and can be customized.

3.Application note

	Integrated Circuit test
	· LED test
	· High Power device test
	· MEMS test
DUT classification	· PCB test
	· LCD Panel test
	· Solar Cell test
	· Material sheet resistivity test
	· RF test
	· Testing in high and low temperature environments
	· Low current (<100fA level) test
Classified by test environment	· IV/CV/P-IV test
	· High Voltage, High Current test
	· Testing under magnetic field
	· Testing under radiation environment test

4.Core advantages

The integration of patented mechanical design, superior components and advanced assembly technology ensures total system's state of the art performance.X12 can ensure high accuracy, fast and reliable testing results, and can improve the wafer process speed and product yield.

The X Series features with the industry' s higher temperature range and test accuracy to match a wide range of test applications.

Note: The default environment is $24\pm2^{\circ}$ C, relative hµmidity is 40% \sim 60%. For other information, please refer to the product manual.



5.Feature description

Ultra-high test precision and efficiency	· Index time ≤500ms
High repeatability and low test cost	· Provide accurate test result, impro
Multi-view optical system	 15:13-zoom microscope, can displ promote manual probing experier
Low noise	·<50dB
Wide range of applications	• Support SiC/GaN wafer testing,hi • Replaceable Chuck design for diffe
Widest temperature range	· -60~200°C, can be customized on
Customized design	 Upgradable to high-power wafer to different testers integration
Mechanical system has the faster speed	• Maximum speed≥70mm/s

6.Equipment models

The X series is available in three models that match the 6/8/12 inch wafer testing . Note: The prober size and weight will be different in the case of prober upgrades or partial customizations.

Model	Wafer size	X-Y axis stroke	Theta angular stroke	Theta Angle resolution	Dimension (mm)	Weight
X6	0-6″	350*365mm	±10°	0.0001°	1060*1610*1500	Approx.1500KG
X8	0-8″	350*365mm	±10°	0.0001°	1060*1610*1500	Approx.1500KG
X12	0-12"	350*365mm	±10°	0.0001°	1060*1610*1500	Approx.1500KG

7.Equipment structure

The equipment consists of software system, chuck system, probing system, visual/optical system, shielding and vibration isolation system.

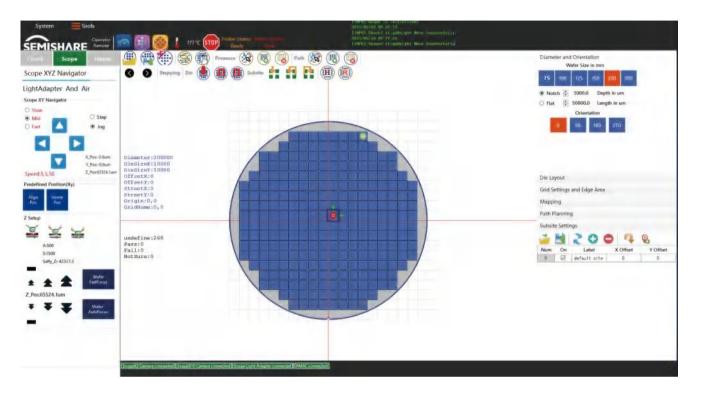
8.Software system

8.1.Wafer test software

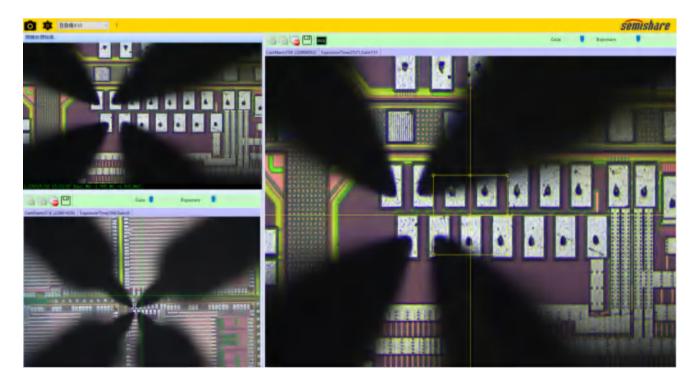
Wafer test software is communicating with testers and controlling the testing process according to testers.

ove wafer processing speed and product yield ${\leqslant}{\pm}1\mu m$
olay low, medium and high magnification simultaneous, ence
igh power wafer testing
ferent wafer testing
n demand
test /RF test /fully automatic test /

8.1.1.Software Interface 1



8.1.2.Software Interface 2



8.1.3.Software Function

1	Support semi-automatic control (available in manual test or upgrade to automatic test
2	Automatic wafer alignment
3	Automatic die size measurement
4	Automatic wafer mapping and remote access of data
(5)	Managing and programming of input and output parameters freely
6	Fast multi-testers integration
7	One-button automatic RF calibration , automatic needle cleaning function
8	Operation system and applications are completely separated; operation system,
	application system and device test system can be upgraded independently
9	Can support single point test and continuous test
(10)	Automatically store data and curves, synchronously process data
1	Classifying test results by different bin values and display different color in wafer map
(12)	Speed limit control and safety interlock

9.Chuck System

9.1.Chuck and four-axis motion control

The XYZ-theta four-axis motion control feedback the tester's results to PC and the inkjet system.

9.2.Characteristics

The bottom plate uses castings through long-time treatment as the basic parts. This thi
In the same time, the compact structure with low center of gravity ensures the acceleration
High-precision stepper actuator + linear sliding mechanism; crossed roller bearing + zer
screw + high-rigidity guide, ensuring total mechanical system micron-accuracy and exce
Each part is treated with a conductive surface to ensure good grounding .

Chuck is electrical floating (can be used as backside electrode during wafer testing)

st)	

ck bottom plate enhances the isolation performance. tion stability during motion.

ro bask lash design; Superior precision grinding ball ellent rigidity.

www.semishareprober.com

X12

Appliable wafer	Wafer size	0-12"
Appliable wafer	Wafer thickness	0mm~2.0mm
	XY motion resolution	0.1µm
	XY positioning repeatability	≪±1µm
	XY positioning accuracy	≪±2μm
	XY travel speed	≥70mm/s
XY axis	X stroke	350mm
AT dXIS	Y stroke	365mm
	Feedback system	0.1µm grating feedback

	Z motion resolution	0.1µm
	Z repeatability	≤±1µm
Z axis	Z positioning accuracy	≤±2µm
	Z travel speed	≥20mm/s
	Z-stroke	20mm
	Travel range	±10°
	Edge shift resolution	0.175µm(0.0001°)
Theta axis	Motion resolution	0.0001°
	Repeatability	$\leqslant \pm 1 \mu$ m(on 300mm Chuck edge)
	Positioning accuracy	\leqslant \pm 2 μ m(on 300mm Chuck edge)
	Rate	≤10°/s

9.4. Chuck temperature control system (optional configuration)

	Туре	6"~12"		
	Temperature control range		-60°C -300	
	Temperature control stability	±0.1°C		
Basic parameters	Minimµm setting of temperature control			
Dusie parameters	Temperature display resolution	0.01°C		
	Noise	<50dB		
	Heating mode		current heating / PID control	
	Cooling mode	Compressor refrige	-	
Timetable	From	То	Time (min)	
	+25 °C	+150°C/+200°C/+300°C	20/25/30	
	0°C	+25 °C	5	
Lipsting Data	-20 °C	+25 °C	8	
Heating Rate	-40 °C	+25 °C	10	
	-55 °C	+25 °C	12	
	-60 °C	+25 °C	15	
	+150°C/+200°C/+300°C	+25 °C	25/30/35	
	+25 °C	0°C	15	
Cooling Rate	+25 °C	-20 °C	25	
cooling hate	+25 °C	-40 °C	35	
	+25 °C	-55 °C	40	
	+25 °C	-60 °C	50	

9.5.Manual Loading, Auxiliary Chuck Module



Structure Description

	a. The wafer is fixed by a central vacuum adsorption hole and multiple vacuum adsorption
	Each vacuµm channel is independently controlled.
	b. Needle cleaning module can clean the foreign matter attached to the needle tip durin
	c. RF Calibration module has independent vacu μm adsorption control, perform RF calibration for the control of the control
	d.Fast roll-out stage, with a large stroke of 370mm, can roll the chuck out of the chambe
	which is convenient for wafer loading.

10.Probe System

10.1.Probe holder

X12 can integrate light wave, microwave, electricity, RF, and high-power test functions. By equipping with corresponding probe holder and tips, X12 can cary out characteristic analysis of -V, C-V, optical signal, RF, 1/F noise on vorious devices and wafers, O-type platform can hold up to 12 probe micro-positioners and tip holders.

10.2.Micro-positioner



Parameter	· Weight	Around 1000 g
	· Dimensions	115L*100W*112H(mm)
	· XYZ Axis stroke	12*12*12(mm)
	· XYZ Motion resolution	0.7µm
	· Base	Magnetic absorption
		with magnetic switch

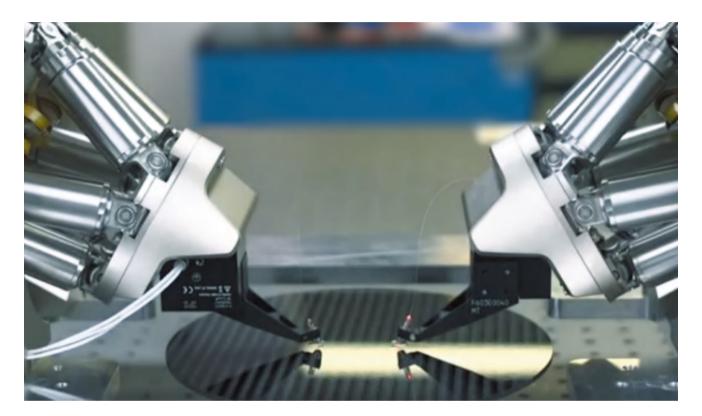
tion rings. ng probe card test. pration before test. er more than 3/4

10.3.Test Module (Optional)

Optical fiber fixture, RF fixture, and high-power fixture can be selected acording to the test application, and probe card test module is optional.

Optional 1: Fiber test module----PI six-axis motion positioner

Alignment of optical components, automatic wafer tests, assembling technology in silicon photonics



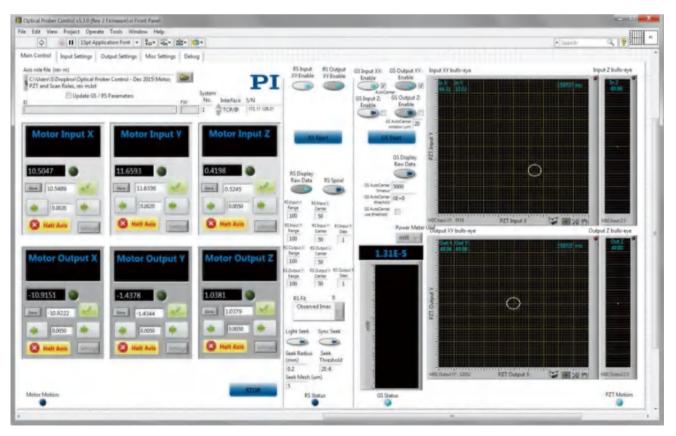
 a. LWP fiber probe and fiber fixture, adjustable incident angle
■ b. PI six-axis positioner

Features and Applications	Integrated scan routines for fiber optic alignment
	Extensive software package
	Position sensors for high accuracy and operational reliability
	Ideal for applications in silicon photonics
	Direct detection of the optical signal
	Automatic alignment of several fibers in <1s

Precision Parameter	Active axes	Х, Ү, Ζ, θх, θу, θz
	Travel range in X, Y, Z	\pm 6.5, \pm 16, \pm 8.5*)(mm)
	Travel range in θΧ, θΥ, θΖ	±14.5, ±10, ±10*(°)
	XYZ repeatability	$\pm 0.15, \pm 0.15, \pm 0.06$
	Repeatability in θΧ, θΥ, θΖ	±2, ±2, ±3

Application Func	tion
Probe	 Correct coupling is difficult and time-consuming.and manual merequired by silicon photonic devices. Even if an automated solution greatly reduces the economics of testing and packaging. PI's alignment automation solution uses an in-depth toolkit base PI's unique full parallel technology can optimize multiple degree channels, and even optimize multiple devices at the same time. pivots to ensure that you can optimize by rotating around the efficiency.
Chip inspection	PI can greatly improve the processing speed of chip inspection, each packaging step and lead to packaging waste.Support custor
Wafer inspection	The structure of silicon photonic components is highly complex, alignment, and multiple channels, all of which need to be optimiz PI can detect the photonic components on the wafer, improve the

PI Software interface

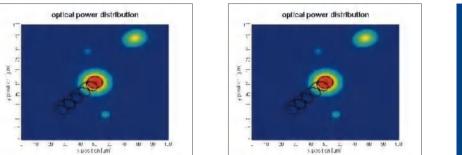


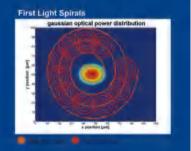
nethods cannot meet the capacity expansion requirements tion is used, a lengthy iterative cycle is still required, which

sed on firmware algorithms to provide precise optimization. rees of freedom, multiple inputs and outputs across e. PI's hexapod-based solution provides freely selectable ne beam waist, focus, or optical axis to further improve

, while ensuring that the product will not be damaged in tomized and embeddable configuration.

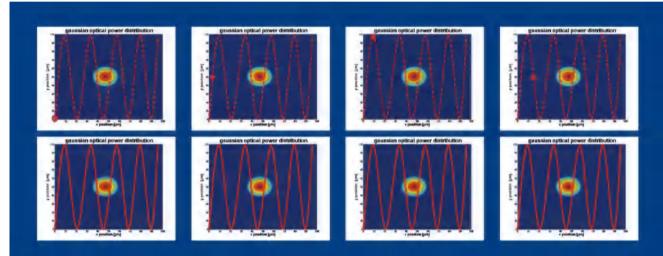
ex, with multiple interacting input and output, component nized in multiple degrees of freedom to ensure detection. ne yield rate, and effectively reduce the cost.





Groundbreaking Built-in-Routines for faster Peak Finding

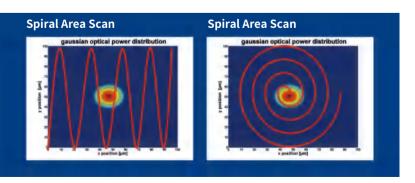
Built-in routines enable extremely high alignment speed. The algorithms for first light, area scan, and gradient search routines are extraordinarily fast and reliable for all kind of couplings. They offer process time of less than 1 second for aligning input and output simultaneously. PI algorithms even include automatic modeling of scan data to accurately localize the optimum even in fast, coarse scans. This includes the ability to rapidly localize the centroid of top-hat couplings – another PI world exclusive.



First Light Scan

In order to determine the global maximum of a signal, it is necessary to make an intensity signal available to the controller that can be optimized. The bult-in frmware algorithms provide all convenient and fast searching for hirt light'. To ensure extremely foast success for firt light searching it is possible to combine several area scan routines for this scan, which can be performed simultaneously.

This can be performed quickly and reliably even for doublesided tasks, where both sides need to be coupled at the same time; the firmware-based algorithms run fully automatically and simultaneously until the predefined threshold value has been reached or the entire area has been scanned. All axes, irrespective of whether they are coarse or fine axes, can be used and configured according to their dynamics. For example, the transmitter side can perform highly dynamic area scans, during which, the receiver side moves slowly but continuously. Therefore, the entire transmitter side is scanned for each and every position on the receiver side. It is also possible to set whether scanning stops as soon as the defined threshold value has been reached or whether the entire area of both sides should be examined.

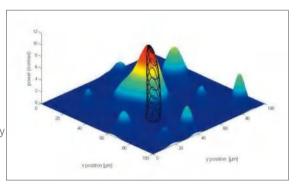


Area Scan Routines

The FMPA system offers 3 different routines for an area scan. The spiral scan with constant angular velocity, the spiral scan with constant path velocity, and the sinusoidal area scan. All routines can be configured individually and therefore optimized for the respective application case. Several scan routines can also be started simultaneously with a single command. It is possible to calculate the approximate maximum using a Gauss function or by determining the centroid. In the case of the sinusoidal scan routine the defined surface is scanned continuously without strong acceleration or deceleration phases. Surface, starting point, line distance, and success criteria can be defined by the user. In the case of the spiral scan routine, a defined area is scanned helically, whereby either a constont angle or a constant path velocity is maintained. The advantage of spiral scanning at a constant frequency is the ability to avoid system resonance. This ensures successful scanning. The advantage of spiral scanning at a constant path velocity is the ablity to reduce the scanning duration in the case of lower system dynamics. Application-specific configuration of the routine is also possible here.

Gradient Search Routines

Ground-breaking results can be achieved with the unique implementation of this algorithm. If the light signal is present, this gradient search makes it possible to find the signal maximpm in less than 1 second even in the case of double-sided tasks. It is also possible to run several searches at the same time and therefore optimize the signal simultaneously in several degrees of freedom. The routine allows excellent "tracking" and therefore it is possible to compensate any drift effects. Several parameters are also available here for optimizing the search for the respective application case.



Optional 2 RF Test Module

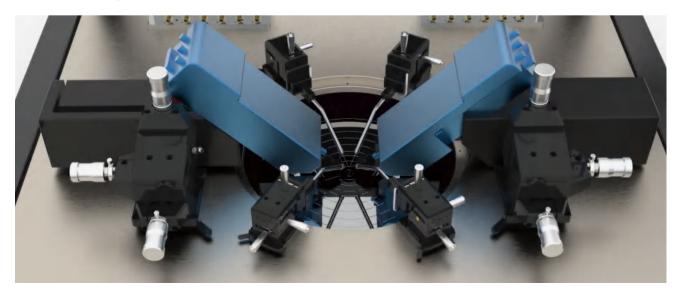
Microwave probe module can be selected according to Pad material and pitch etc.



Structure Description

a. RF Probe b.RF Probe fixture d. Magnetic adsorption base

RF cable and positioner



c.SS-100 XYZ adjustment mechanism

Test precision

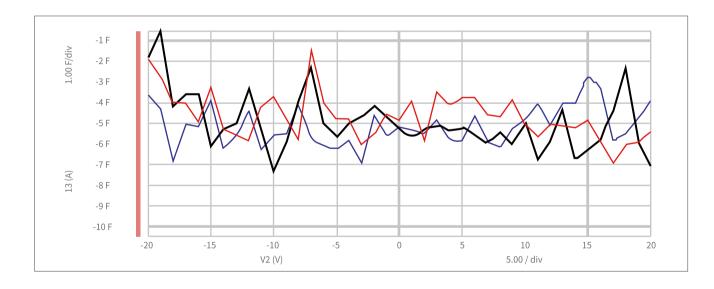
<10fA very low electric current design	
Characteristic Dual SSMC con	Dual SSMC connection for quasi-Kelvin connection of SMU and LCR
endracteristic	Replaceable coaxial probe design, easy to replace the damaged probe or change to a different radius size

Kelvin tips holder

	■ Low current (SMU)(<10fA)	11
Functional	■ LCR (<10fF)	
Application	signal integrity	
	Pulse source / sensing	
	TLP(10ns rise, 76LWA ground loop)	

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Current Leakage: Leakage ≤±10fA or Leakage ≤±100fA @-60°C~+200°C by using different tips holders and chuck.



Other positioners and tip holder

Positioner specifications	SS-700 type	SS-100 type	SS-40 type
Dimensions(W*D*H)	148mm*120 mm*140mm	115mm*100mm*112mm	64mm*47mm*66mm
Weight	1500g	1000g	200g
Precision	0.1micron	0.7 micron	10 micron
Screw thread	700TPI	100TPI	40TPI
X-Y-Z linear stroke	12 mm*12 mm*12 mm	12mm*12mm*12mm	12mm*12mm*12mm

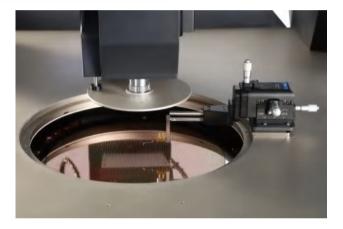
Triaxial, Coaxial, Spring, Tubular Fixture

A mechanism mounted on the micro-positioner that hold the tip and transit signal from tip to tester through high shielding calbes . It moves together with micro-positioner's X-Y-Z.

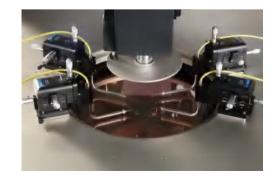




Installation example



According To	Spring type: Fix the probe in the pinhole by spring backend). Easy to use, suitable for short-term high leakage under 10PA, BNC male output connector.
Mechanical Structure	Tubular type: Fix the probe by the inner copper tube, a there is insulation between the inner and outer copper cable at the backend.) current leakage <100fA, highes
According To current	Coaxial tip holder: Connect to 1.2m BNC interface of shielding box, the electrical current leakage<10pA, the
leakage Accuracy	 Triaxial tip holder : Connect to 2m triaxial interface cal box, the electrical current leakage<100fA, the frontend recommended for SS-40 small micro-positioner)



Tip holder selection procedure

Select a probe holder model according to the size of pad \rightarrow select cable model according to the electrical test accuracy \rightarrow select mechanical fixture model according to the mechanical precision and electrical test accuracy.

Probe card holder

It is suitable for 4.5" standard pin card fixture, and can be customized design and production according to demand.

g elasticity (connect coaxial or triaxial cable at the h current (<1A), high stability coaxial cable, current

, and the outer copper tube shields the noise interference; ver tubes (can connect to ordinary cable, coaxial or triaxial est voltage is 1000V with shield box.

e coaxial cable at back end. When using the standard e front end fixture is available in spring or tubular type.

cable at back end. When using the standard shielding nd fixture is available in spring or tubular type. (Not

10.4. Vision/Optical System

Visual System

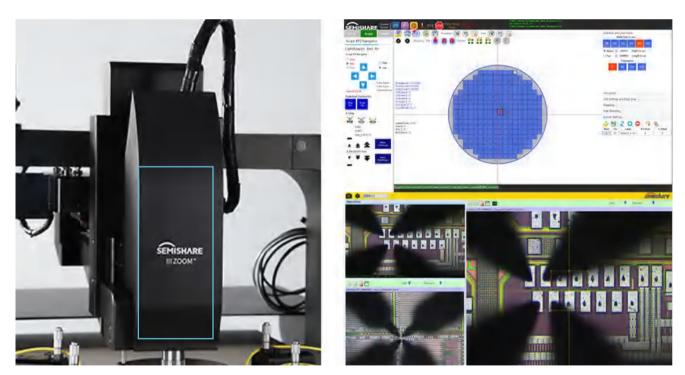
The system composed of Basler 2-megapixel digital camera, Mitutoyo high resolution lens and SEMISHARE independently developed 3-zoom microscope for multi-view and high resolution image output.

Characteristic	 Optical image identification, automatic wafer alignment
	SEMI digital computing model, precise positioning
	■ 32-bit color CMOS chips
	Gigabit network mode communication interface

Optical microscope

The microscope is configured as SEMISHARE 3-zoom concentric focal microscope and side-view microscope (optional for tip contact observation). Among them, the 3-zoom microscope is developed by SEMISHARE independently, which provides three different imaging magnifications without switching any lens. The three magnifications can meet most requirements of tested samples, with high compatibility and significantly improve the efficiency of test.

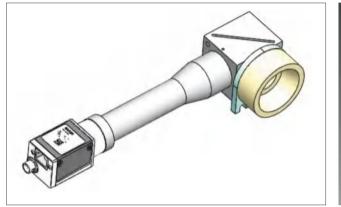
3-zoom concentric focal microscope

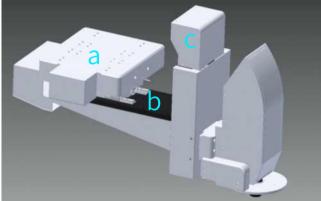


	■ Mitutoyo 5X (replaceable 2-50X) objectives	Magnification 0.6*5x/2.5*5x/9*5x
Configuration	Basler CMOS	2 Megapixel / high speed / 23" display
	■ Final imaging Magnification(use 5X objectives)	Magnification 100x/450x/1600x

Side-view microscope (Option)

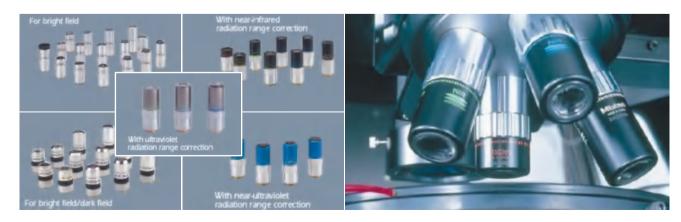
It uses independent telecentric lens and coaxial illumination to observe real-time contact of probe tip to wafer in a long distance and wide range.





	THK high rigidity and high precision guide and screw are used for linear motion		
Characteristics	Renishaw 0.1µm resolution grating is used, combined with high performance motion control card,		
	and form closed-loop feedback system with the motor		
	High stability and ultra-high precision motion control		
	XY motion resolution	0.1µm	
	XYZ speed	≤15mm/s	
Precision Parameter	XY stroke range	50.8mm*50.8mm (2"*2")	
	Z stroke range	125mm (5")	
	Travel resolution	0.1µm	

Objective



3 zoom Microscope motion system (triaxial control system) Position Indication: a. is the X axis b. is the Y axis c. is the Z axis

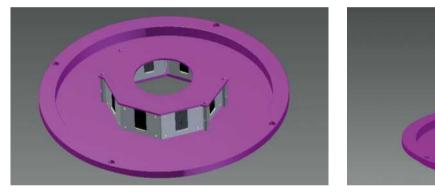
Characteristics	Long working distance for easy probing		
	 Additional installation of polarized light or multi-wavelength cutting lasers 		
Parameters	Objective magnification 2X	Working distance 34mm	
	Objective magnification 10X	Working distance 33.5mm	
	Objective magnification 20x	Working distance 20mm	
	Objective magnification 50X	Working distance 20.5mm	
	Objective magnification 100X	Working distance 13mm	

Shielding and vibration isolation system

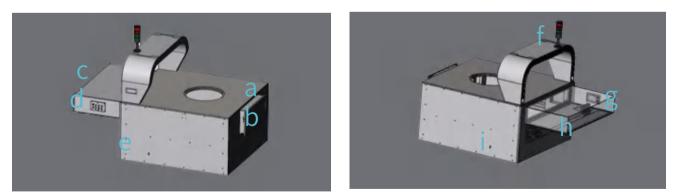
Probe station shielding system

The shielding assembly is constituted of an octagonal box and chamber to shield internal and external noise for low current test, the chamber is almost a hermetic cavity filled dry air for high and low temperature wafer test .

Octagonal box



Chuck cavity



Structure Description	a. Shield cavity table	b. Shielded front door
	c. Back cover	d. Vacuµm transfer
	e. Shield cavity side	f. Gantry rack
	g. Refrigeration gas transfer	h. Dry air hµmidity sensor
	i. Hermitic communication adapter	

Shielding Parameter	EMI shield	>30 dB (typical)@ 1 kHz to 1 MHz			
	Light attenuation	≥130 dB			
	Spectral noise floor	≤-180 dB Vrms/rtHz(≤1 MHz)			
	System AC noise	\leqslant 5 mVp-p (\leqslant 1 GHz)			
Characteristic	Conductive oxidation and nickel plating surface treatment to ensure the conduction state between the				
	parts for the full shielding .				
	High and low temperatures capability, dry air purge into the chamber during low temperature test				
	process to prevent external vapor from entering the cavity and causing condensation/frost on the wafer .				
	Light shielding .				

Damping system

Passive air membrane isolation system and a casting is used as substrate to maintain the stability of the entire system during high speed motion.

Passive air membrane isolation airbag

	Parameters	Vibration isolation mode	Air cushion film shock absorption ensures that the image is not shaken at 2000x magnification
		Inherent frequency	2.3~2.6Hz(verticalhorizontal)
		Roll-Roll Rate (10Hz)	Over 20-24dB
		Horizontal mode	Automatic leveling system with 3 balance valves
		Horizontal reset precision	±0.05/±0.1
		Working conditions	4~6Kg compressed air or liquid nitrogen
		Damping mode	air

High precision regulating valve



Other Configuration

Safety system

Optional safety IR light curtain or safety sensor, real-time monitoring of operating status, and immediately stop the prober when an abnormal situation happens.

Operating System

 \cdot PC configurations 2 x 23' display, I7 CPU PC, 1TB hard drive, 8G memory, 1G discrete graphics, wireless mouse, GPIB communication interface

 \cdot Operation desk: It has independent flexible operation desk, manual control box (optional).

Physical parameter

X12 System dimensions (W x D x H)1060*1610*1500(mm) Weight 1500KG

*Can increase depends on operator manual adjustment or interaction.

